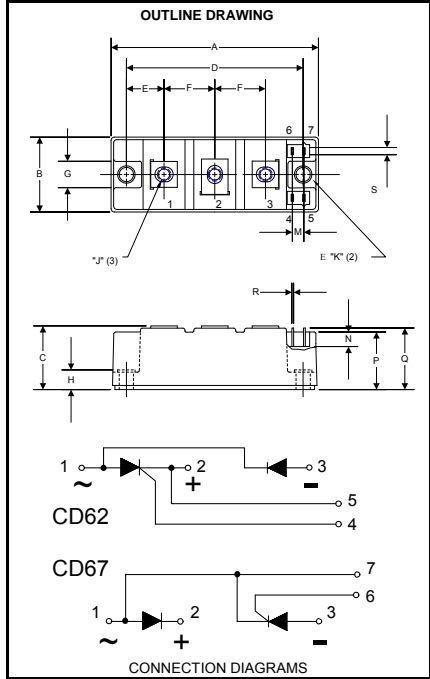


**POW-R-BLOK™**  
**Dual SCR/Diode Isolated Module**  
**150 Amperes / Up to 1800 Volts**



**CD62\_\_15B, CD67\_\_15B**  
**Dual SCR/Diode Isolated**  
**POW-R-BLOK™ Module**  
150 Amperes / Up to 1800 Volts

**Description:**

Powerex SCR/Diode Modules are designed for use in applications requiring phase control and isolated packaging. The modules are isolated for easy mounting with other components on a common heatsink. *POW-R-BLOK™* has been tested and recognized by the Underwriters Laboratories.

**Features:**

- Electrically Isolated Heatsinking
- DBC Alumina (Al<sub>2</sub>O<sub>3</sub>) Insulator
- Glass Passivated Chips
- Metal Baseplate
- Low Thermal Impedance for Improved Current Capability
- Quick Connect Gate Terminal with Provision for Keyed Mating Plug
- UL Recognized (E78240)

**Benefits:**

- No Additional Insulation Components Required
- Easy Installation
- No Clamping Components Required
- Reduce Engineering Time

**Applications:**

- Bridge Circuits
- AC & DC Motor Drives
- Battery Supplies
- Power Supplies
- Large IGBT Circuit Front Ends
- Lighting Control
- Heat & Temperature Control
- Welders

**CD62\_\_15B, CD67\_\_15B**

**Outline Dimensions**

Dimension	Inches	Millimeters
A	3.70	94
B	1.38	35
C	1.18	30
D	3.15	80
E	0.67	17
F	0.91	23
G	0.57	14.5
H	0.35	9
J	M6	M6
K	0.26	6.5
M	.020	5
N	0.28	7
P	1.10	28
Q	1.14	29
R	0.03	0.8
S	0.11	2.8

Note: Dimensions are for reference only.

**Ordering Information:**

Select the complete nine digit module part number from the table below.  
Example: CD621615B is a 1600Volt, 150 Ampere SCR/Diode Isolated *POW-R-BLOK™* Module

Type	Voltage Volts (x100)	Current Amperes (x 10)	Version
CD62	08	15	B
CD67	12		
	14		
	16		
	18		

**Absolute Maximum Ratings**

Characteristics	Conditions	Symbol	Units
Repetitive Peak Forward and Reverse Blocking Voltage		$V_{DRM}$ & $V_{RRM}$	up to 1800 V
Non-Repetitive Peak Reverse Blocking Voltage (t < 5 msec)		$V_{RSM}$	$V_{RRM} + 100$ V
RMS Forward Current	180° Conduction, $T_C=85^\circ\text{C}$	$I_{T(RMS)}$	250 A
	180° Conduction, $T_C=85^\circ\text{C}$ (AC Switch)	$I_{T(RMS)}$	355 A
Average Forward Current	180° Conduction, $T_C=85^\circ\text{C}$	$I_{T(AV)}$	160 A
	180° Conduction, $T_C=90^\circ\text{C}$	$I_{T(AV)}$	150 A
Peak One Cycle Surge Current, Non-Repetitive	60 Hz, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	3700 A
	60 Hz, No $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	5250 A
	50 Hz, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	3520 A
	50 Hz, No $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	5000 A
Peak Three Cycle Surge Current, Non-Repetitive	60 Hz, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	2970 A
	50 Hz, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	2830 A
Peak Ten Cycle Surge Current, Non-Repetitive	60 Hz, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	2335 A
	50 Hz, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I_{TSM}$	2830 A
$I^2t$ for Fusing for One Cycle	8.3 ms, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I^2t$	57,040 A <sup>2</sup> sec
	8.3 ms, No $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I^2t$	114,840 A <sup>2</sup> sec
	10 ms, 100% $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I^2t$	61,950 A <sup>2</sup> sec
	10 ms, No $V_{RRM}$ reapplied, $T_j=125^\circ\text{C}$	$I^2t$	125,000 A <sup>2</sup> sec
Maximum Rate-of-Rise of On-State Current, Non Repetitive	$T_j=125^\circ\text{C}$ , $V_D=1.0 V_{DRM}$ (Rated), $I_{TM}=400\text{A}$ , $I_G=0.5\text{A}$ , $T_r < 0.25\mu\text{s}$ , $t_p > 6\mu\text{s}$	di/dt	300 A/ $\mu\text{s}$
Peak Gate Power Dissipation	$T_p < 5\text{ms}$ , $T_j = 125^\circ\text{C}$	$P_{GM}$	12 W
Average Gate Power Dissipation	$F = 50\text{Hz}$ , $T_j = 125^\circ\text{C}$	$P_{G(AV)}$	3 W
Peak Forward Gate Current	$T_p < 5\text{ms}$ , $T_j = 125^\circ\text{C}$	$I_{GFM}$	3 A
Peak Reverse Gate Voltage	$T_p < 5\text{ms}$ , $T_j = 125^\circ\text{C}$	$V_{GRM}$	10 V
Operating Temperature		$T_J$	-40 to +125 °C
Storage Temperature		$T_{stg}$	-40 to +125 °C
Max. Mounting Torque, M6 Mounting Screw on Terminals			35 - 50 in.-Lb.
			4 - 6 Nm
Max. Mounting Torque, Module to Heatsink			35 - 50 in.-Lb.
			4 - 6 Nm
Module Weight, Typical			165 G
			5.82 Oz.
V Isolation @ 25C	$T_j = 25^\circ\text{C}$ , 1 second	$V_{rms}$	3600 V
	$T_j = 25^\circ\text{C}$ , 1 minute	$V_{rms}$	3000 V

**Electrical Characteristics, T<sub>J</sub>=25°C unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Forward Leakage Current	I <sub>DRM</sub>	Up to 1600V, T <sub>J</sub> =125°C		50	mA
Repetitive Peak Reverse Leakage Current	I <sub>RDM</sub>	Up to 1600V, T <sub>J</sub> =125°C		50	mA
Peak On-State Voltage	V <sub>TM</sub> / V <sub>FM</sub>	I <sub>TM</sub> / I <sub>FM</sub> = 500A		1.6	V
Threshold Voltage, Low-level	V <sub>(TO)1</sub>	T <sub>J</sub> = 125°C, I = 16.7% x πI <sub>T(AV)</sub> to πI <sub>T(AV)</sub>		0.85	V
Slope Resistance, Low-level	r <sub>T1</sub>			1.5	mΩ
Minimum dV/dt	dV/dt	Exponential to 2/3 V <sub>DRM</sub> T <sub>J</sub> =125°C, Gate Open	1000		V/μs
Turn-Off Time (Typical)	t <sub>off</sub>	T <sub>J</sub> = 125°C, I <sub>T</sub> = 300A, R <sub>gk</sub> = 100Ω V <sub>r</sub> = 50V, -dI/dt=15 A/μs Re-Applied dV/dt = 20V/μs, Linear to 2/3 V <sub>DRM</sub>	50 - 200	(Typical)	μs
Gate Trigger Current	I <sub>GT</sub>	T <sub>J</sub> = 25°C, V <sub>D</sub> =6V, R <sub>a</sub> =1Ω Resistive Load		150	mA
Gate Trigger Voltage	V <sub>GT</sub>	T <sub>J</sub> = 25°C, V <sub>D</sub> =6V, R <sub>a</sub> =1Ω, Resistive Load		2.0	Volts
Non-Triggering Gate Voltage	V <sub>GDM</sub>	T <sub>J</sub> =125°C, V <sub>D</sub> =V <sub>DRM</sub>		0.25	Volts
Non-Triggering Gate Current	I <sub>GDM</sub>	T <sub>J</sub> =125°C, V <sub>D</sub> =V <sub>DRM</sub>		10	mA
Holding Current	I <sub>H</sub>	T <sub>J</sub> =25°C	150	(Typical)	mA
Latching Current	I <sub>L</sub>	T <sub>J</sub> =25°C	300	(Typical)	mA

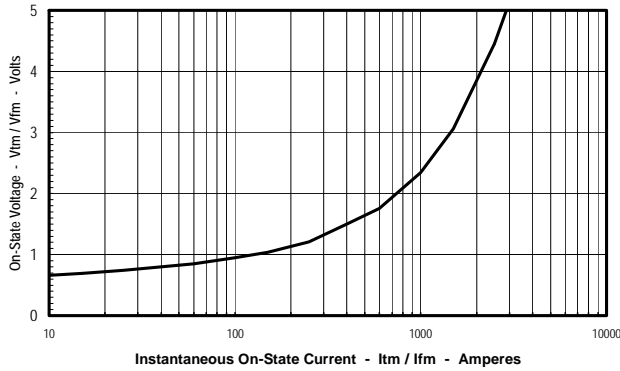
**Thermal Characteristics**

Characteristics	Symbol	Test Conditions	Max.	Units
Thermal Resistance, Junction to Case DC Operation	R <sub>ΘJ-C</sub>	Per Module, both conducting Per Junction, both conducting	0.085 0.17	°C/W °C/W
Thermal Resistance, Case to Sink Lubricated	R <sub>ΘC-S</sub>	Per Module	0.05	°C/W

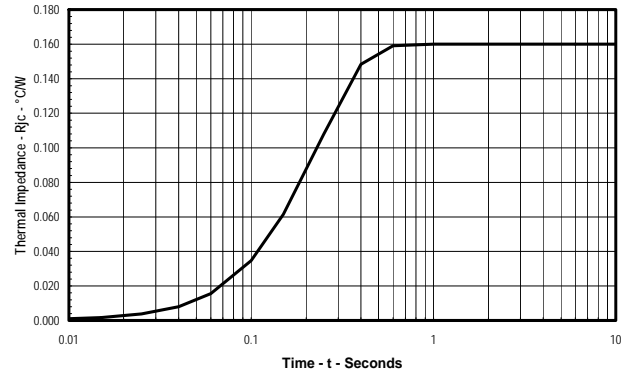
Information presented is based upon manufacturers testing and projected capabilities.  
 This information is subject to change without notice.  
 The manufacturer makes no claim as to the suitability of use, reliability, capability,  
 or future availability of this product.

**POW-R-BLOK™**  
Dual SCR/Diode Isolated Module  
150 Amperes / Up to 1800 Volts

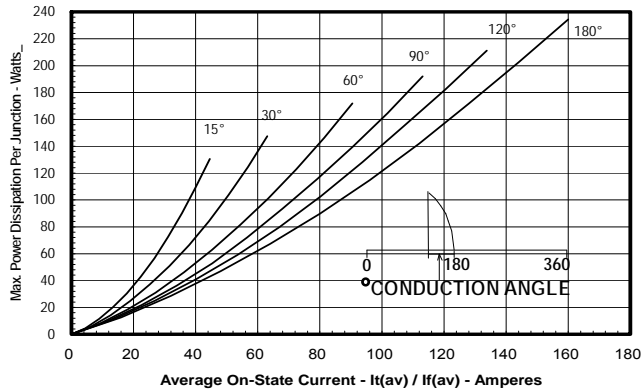
**Maximum On-State Forward Voltage Drop**  
( $T_j = 125^\circ\text{C}$ )



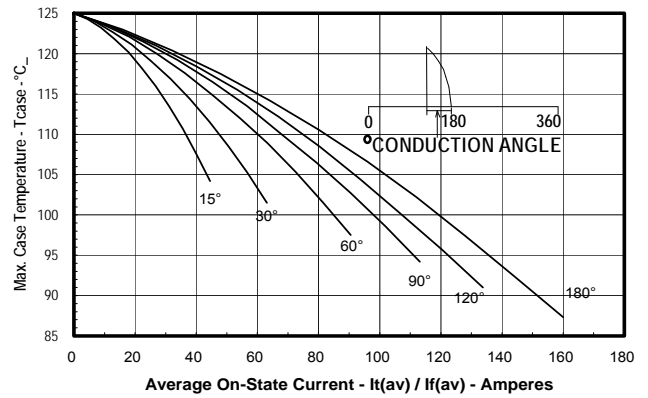
**Maximum Transient Thermal Impedance**  
(Junction to Case)



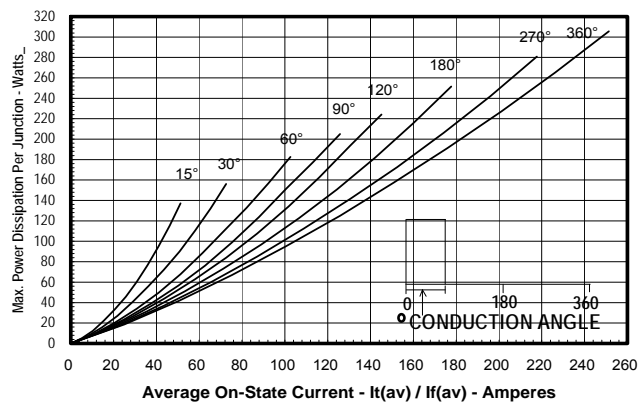
**Maximum On-State Power Dissipation**  
(Sinusoidal Waveform)



**Maximum Allowable Case Temperature**  
(Sinusoidal Waveform)



**Maximum On-State Power Dissipation**  
(Rectangular Waveform)



**Maximum Allowable Case Temperature**  
(Rectangular Waveform)

